

MiniSKiiP[®] 2 Dual

Half-Bridge

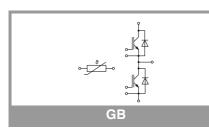
SKiiP 26GB12F4V1

Features*

- Fast Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for
- electrical connectionsUL recognised: File no. E63532
- NTC T-Sensor
- NTC 1-Sensor

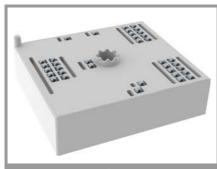
Remarks

- Max. case temperature limited to T_C= 125°C
- Product reliability results valid for $T_j \le 150^{\circ}C$ (recommended $T_{j,op} = -40...+150^{\circ}C$)



Absolute	Maximum Rating	6			
Symbol	Conditions		Values	Unit	
Inverter -	IGBT				
V _{CES}	T _j = 25 °C		1200	V	
Ic	λ _{paste} =0.8 W/(mK)	T _s = 25 °C	197	Α	
	T _j = 175 °C	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Α		
I _C	λ _{paste} =2.5 W/(mK)	T _s = 25 °C	257	Α	
	T _j = 175 °C	T _s = 70 °C	208	Α	
I _{Cnom}			200	Α	
I _{CRM}			400	Α	
V _{GES}			-20 20	V	
t _{psc}	$V_{CC} = 800 V$ $V_{GE} \le 15 V$ $V_{CES} \le 1200 V$	T _j = 150 °C	10	μs	
Tj		-	-40 175	°C	
Inverse -	Diode				
IF	λ _{paste} =0.8 W/(mK)	T _s = 25 °C	194	Α	
	T _j = 175 °C	T _s = 70 °C	154	Α	
I _F	λ _{paste} =2.5 W/(mK)	T _s = 25 °C	219	Α	
	T _j = 175 °C		174	Α	
I _{FRM}			400	Α	
I _{FSM}	10 ms, sin 180°, T _i = 150 °C		990	Α	
Tj			-40 175	°C	
Module				•	
I _{t(RMS)}	T _{terminal} = 80 °C, 20	A per spring	200	Α	
T _{stg}	module without TIM		-40 125	°C	
Visol	AC sinus 50 Hz, t = 1 min		2500		

Characte	eristics					
Symbol	Conditions		min.	typ.	max.	Unit
Inverter -	IGBT		•			
V _{CE(sat)}	$I_{\rm C} = 200 {\rm A}$	T _j = 25 °C		2.05	2.42	V
	V _{GE} = 15 V chiplevel	T _j = 150 °C		2.59	2.96	V
V _{CE0} chiplevel	chinlevel	T _j = 25 °C		1.10	1.28	V
	Chiplevel	T _j = 150 °C		0.95	1.13	V
r _{CE} V _{GE} = 15 V	T _j = 25 °C		4.8	5.7	mΩ	
	chiplevel	T _j = 150 °C		8.2	9.2	mΩ
V _{GE(th)}	$V_{GE} = V_{CE}, I_C = 7.6$	mA	5.2	5.8	6.4	V
I _{CES}	$V_{GE} = 0 V, V_{CE} = 12$	00 V, T _j = 25 °C			2.0	mA
C _{ies}	V _{CE} = 25 V V _{GF} = 0 V	f = 1 MHz		12.30		nF
C _{oes}		f = 1 MHz		0.81		nF
C _{res}		f = 1 MHz		0.69		nF
Q _G	V _{GE} = - 8 V+ 15 V			1134		nC
R _{Gint}	T _j = 25 °C			3.8		Ω
t _{d(on)}	$l_{\rm C} = 200 {\rm A}$	T _j = 150 °C		167		ns
t _r		T _j = 150 °C		52		ns
Eon		T _j = 150 °C		16.8		mJ
t _{d(off)}		T _j = 150 °C		414		ns
t _f		T _j = 150 °C		52		ns
E _{off}	V _{GE} = +15/-15 V	T _j = 150 °C		16.3		mJ
R _{th(j-s)}	per IGBT, λ _{paste} =0.8	3 W/(mK)		0.25		K/W
R _{th(j-s)}	per IGBT, $\lambda_{\text{paste}}=2.5$	5 W/(mK)	1	0.16		K/W



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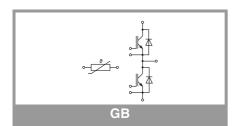
Features*

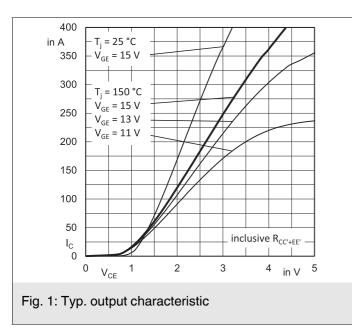
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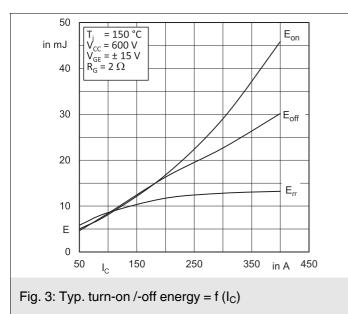
Remarks

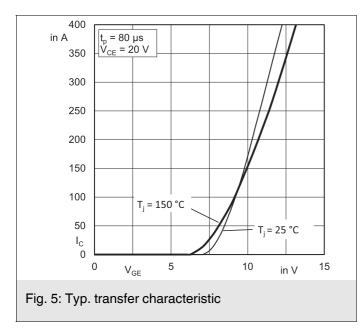
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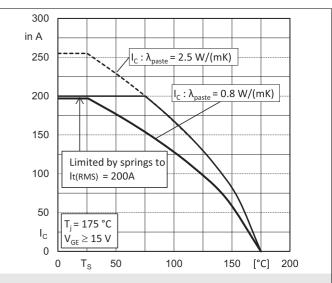
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Symbol	Conditions		min.	typ.	max.	Unit
Inverse -	Diode					
$V_F = V_{EC}$	I _F = 200 A	T _j = 25 °C		2.20	2.52	V
	Diode $I_{F} = 200 \text{ A}$ $V_{GE} = 0 \text{ V}$ chiplevel chiplevel chiplevel I_{F} = 200 \text{ A} chiplevel I_{F} = 200 \text{ A} di/dt_{off} = 3840 \text{ A/}\mu\text{s}} V_{GE} = -15 \text{ V} V_{CC} = 600 \text{ V} per Diode, λ_{paste} =0.8 per Diode, λ_{paste} =2.5	T _j = 150 °C		2.15	2.47	V
V _{F0} chiplevel	obiploval	T _j = 25 °C		1.30	1.50	V
	chipievei	T _j = 150 °C		0.90	1.10	V
r _F	chiplevel	T _j = 25 °C		4.5	5.1	mΩ
		T _j = 150 °C		6.3	6.9	mΩ
I _{RRM}	di/dt _{off} = 3840 A/µs V _{GE} = -15 V	T _j = 150 °C		189		Α
Q _{rr}		T _j = 150 °C		28.7		μC
E _{rr}		T _j = 150 °C		11.7		mJ
R _{th(j-s)}	per Diode, $\lambda_{\text{paste}}=0$.	8 W/(mK)		0.34		K/W
R _{th(j-s)}	per Diode, λ_{paste} =2.5 W/(mK)		0.28			K/W
Module						
L _{CE}				20		nH
Ms	to heat sink		2		2.5	Nm
w				50		g
Temperat	ure Sensor					
R ₁₀₀	T _c =100°C (R ₂₅ =5 kΩ)		493 ± 5%			Ω
B _{25/85}	R _(T) =R ₂₅ *exp[B _{25/85}	*(1/T-1/298)], T[K]	3420			K

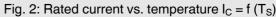


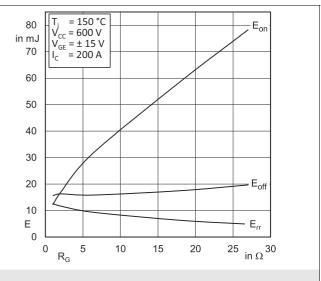


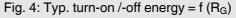


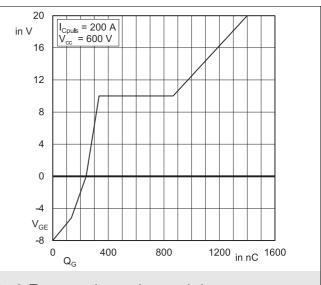


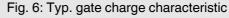


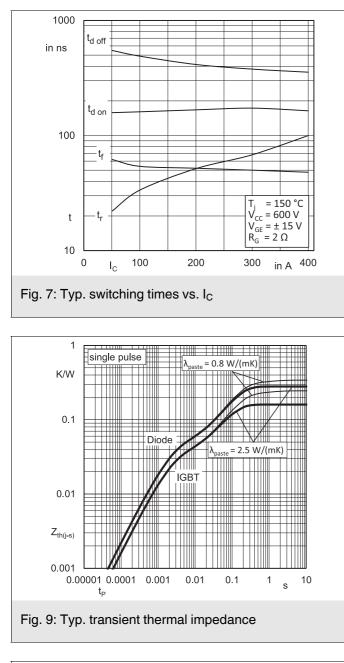


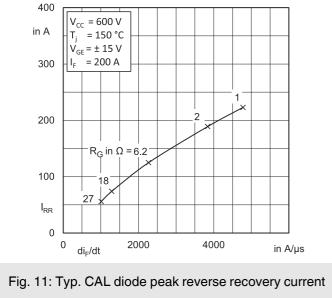












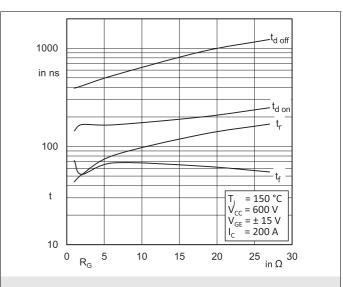


Fig. 8: Typ. switching times vs. gate resistor R_G

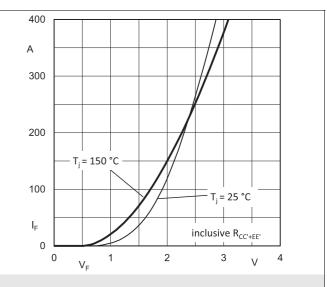
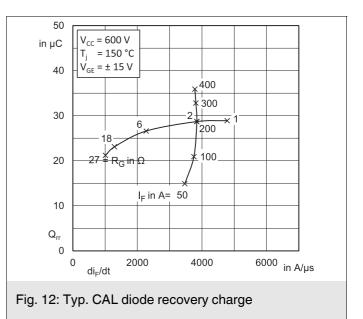
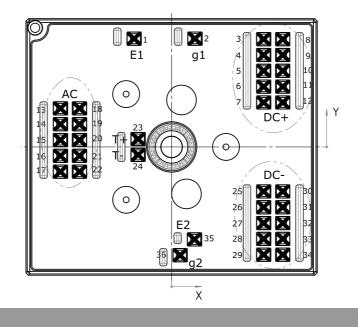


Fig. 10: Typ. CAL diode forward characteristic

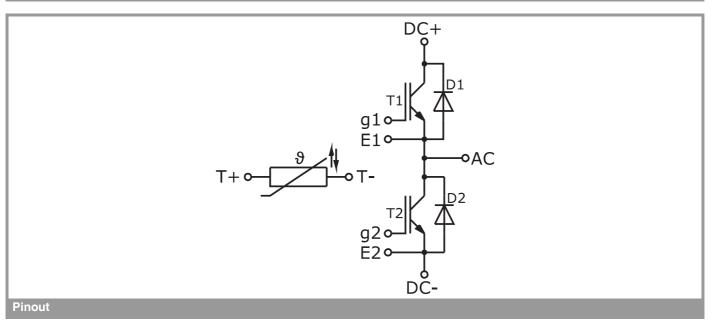


Pin out							
Pin	X	Y	Function	Pin	X	Y	Function
1	-7,58	21,9	E1	19	-18,63	4,6	AC
2	4,73	21,9	g1	20	-18,63	1,4	AC
3	18,63	21,8	DC+	21	-18,63	-1,8	AC
4	18,63	18,6	DC+	22	-18,63	-5	AC
5	18,63	15,4	DC+	23	-6,78	1,6	T+
6	18,63	12,2	DC+	24	- 6,78	-1,6	Т-
7	18,63	9	DC+	25	18,63	-9	DC-
8	22,48	21,8	DC+	26	18,63	-12,2	DC-
9	22,48	18,6	DC+	27	18,63	-15,4	DC-
10	22,48	15,4	DC+	28	18,63	-18,6	DC-
11	22,48	12,2	DC+	29	18,63	-21,8	DC-
12	22,48	9	DC+	30	22,48	-9	DC-
13	-22,48	7,8	AC	31	22,48	- 12,2	DC-
14	-22,48	4,6	AC	32	22,48	-15,4	DC-
15	-22,48	1,4	AC	33	22,48	-18,6	DC-
16	-22,48	-1,8	AC	34	22,48	- 21,8	DC-
17	-22,48	-5	AC	35	4,63	-18,7	E2
18	-18,63	7,8	AC	36	1,73	-21,9	g2

all values in [mm]



Pinout and Dimensions



This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

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